Product Overview

The CMD282 is negative controlled, wideband GaAs MMIC 2-bit digital attenuator die which operates from DC to 40 GHz. Each bit of the attenuator is controlled by a single voltage of either 0 V or -5 V. The attenuator bit values are 4 dB and 8 dB, for a total attenuation of 12 dB. The CMD282 has a low insertion loss of 1.5 dB at 18 GHz and the attenuation accuracy is typically 0.1 dB step error. The CMD282 is a 50 ohm matched design which eliminates the need for RF port matching. The CMD282 offers full passivation for increased reliability and moisture protection.
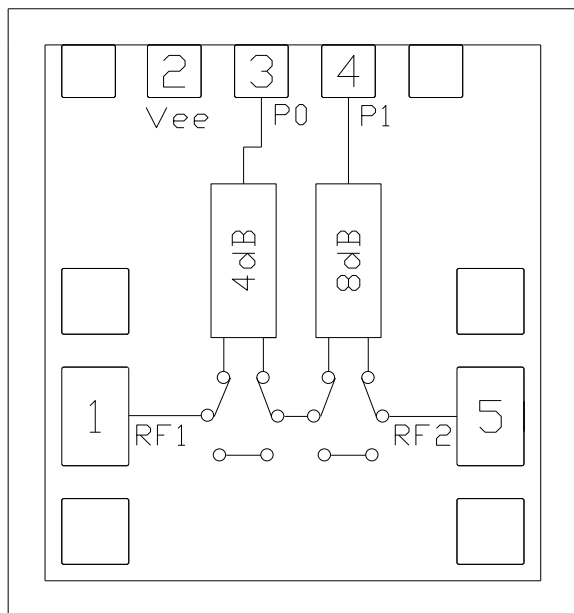
Key Features

- Ultra Wideband Performance
- Low Insertion Loss
- Wide Attenuation Range
- Small Die Size

Ordering Information

Part No.	Description
CMD282	100 pcs in gel pack

Functional Block Diagram

Electrical Performance (V_{ee} = -5 V, V_{ctl} = 0 / -5 V, T_A = 25º C, F = 18 GHz)

Parameter	Min	Typ	Max	Units
Frequency Range		DC - 40		GHz
Insertion Loss		1.5		dB
Attenuation Range		12		dB
Input Return Loss		18		dB
Output Return Loss		18		dB
Input P0.1dB		23		dBm
Input IP3		42		dBm
Switching Speed		25		ns

Absolute Maximum Ratings

Parameter	Rating
Bias Voltage, V_{ee}	-8 V
Control Voltage, V_{ctl}	-8 V
RF Input Power	+27 dBm
Thermal Resistance, Q_{JC}	125.32° C/W
Operating Temperature	-55 to 85° C
Storage Temperature	-55 to 150° C

Exceeding any one or combination of the maximum ratings may cause permanent damage to the device.

Recommended Operating Conditions

Parameter	Min	Typ	Max	Units
V_{ee}	-5.5	-5	-2.5	V

Electrical performance is measured at specific test conditions. Electrical specifications are not guaranteed over all recommended operating conditions.

Truth Table

Control Voltage Input		Attenuation State RF1 - RF2 (dB)
P0 4 dB	**P1 8 dB**	
Low	Low	Reference (insertion loss)
High	Low	4
Low	High	8
High	High	12

Any combination of the above states will result in an attenuation approximately equal to the sum of the bits selected.

Control Voltage

State	Bias Condition
High	$V_{ee} \pm 0.3$ V
Low	0 ± 0.3 V

Electrical Specifications (V_{ee} = -5 V, V_{ctl} = 0 / -5 V, T_A = 25° C)

| Parameter	Min	Typ	Max	Min	Typ	Max	Units
Frequency Range		DC - 25			25 - 40		GHz
Insertion Loss		1.5	2.2		2	3.1	dB
Attenuation Range		12			12		dB
Attenuation Accuracy		0.5	1		0.2	0.5	dB
Input Return Loss		18			13		dB
Output Return Loss		18			13		dB
Input P0.1dB		23			23		dBm
Input IP3		42			42		dBm

Note: Specification applies to major states

Typical Performance

Insertion Loss versus Temperature
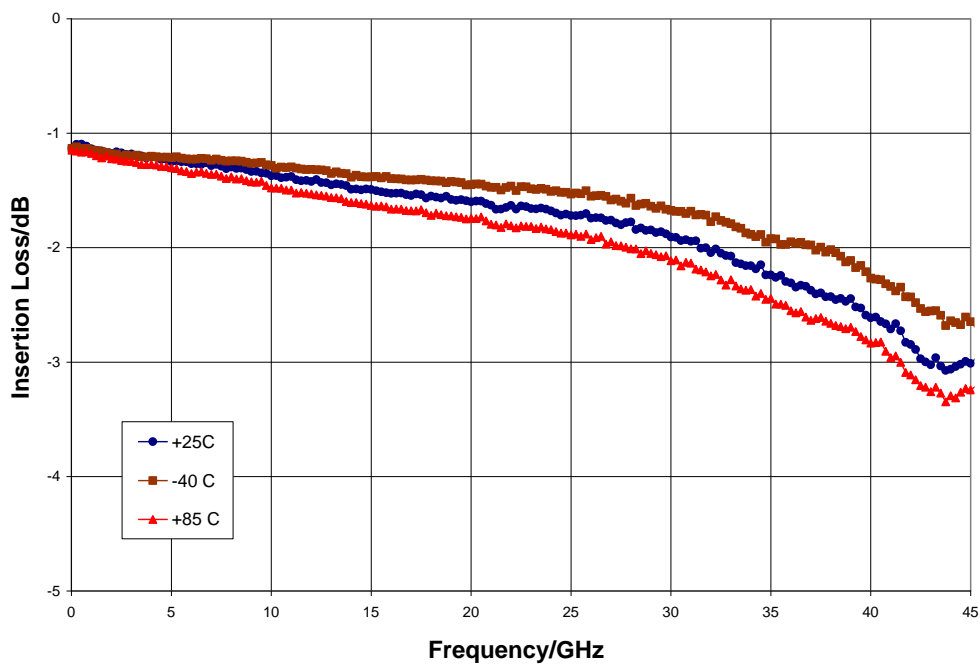
Normalized Attenuation (all states), T_A = 25° C
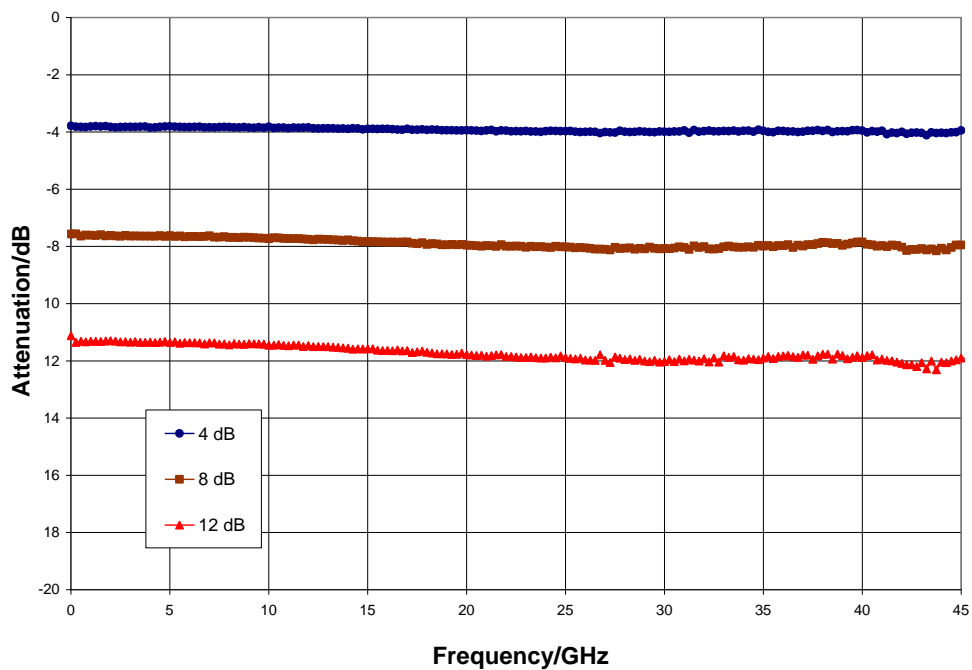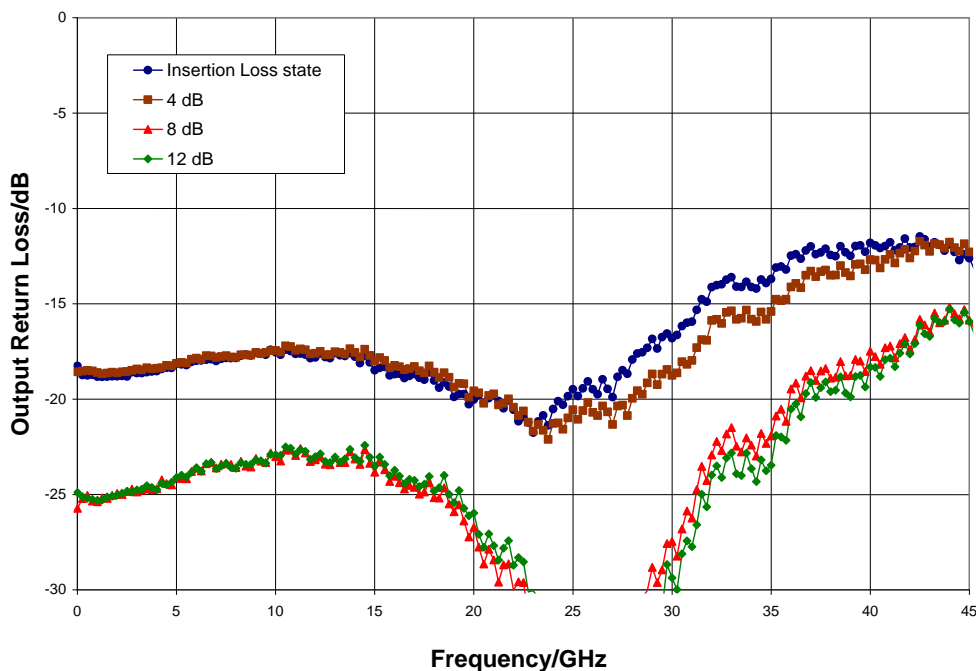
Typical Performance

Input Return Loss (all states), T$_A$ = 25° C
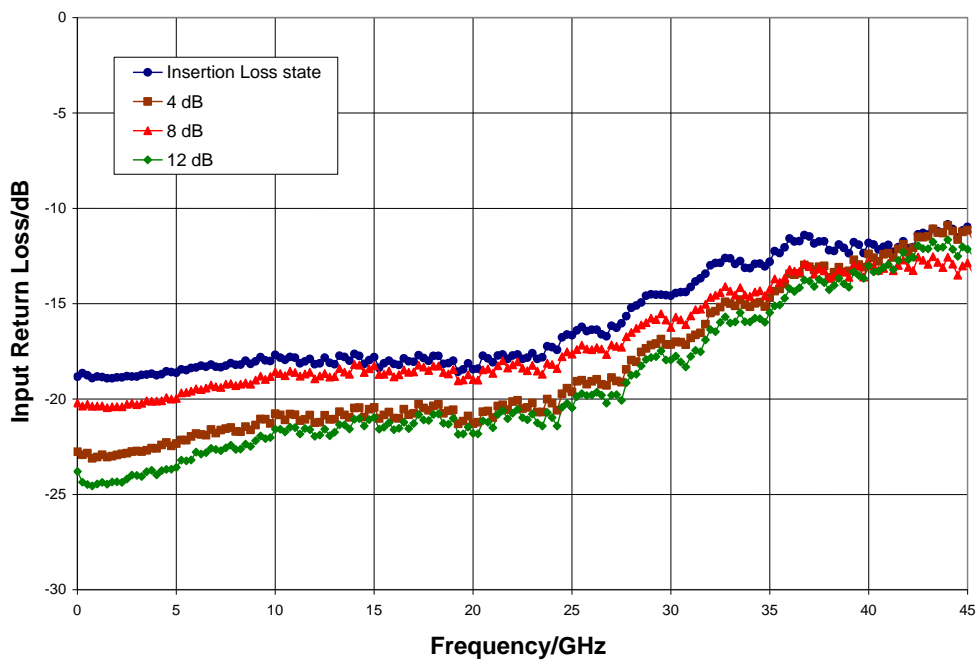
Output Return Loss (all states), T$_A$ = 25° C

Typical Performance
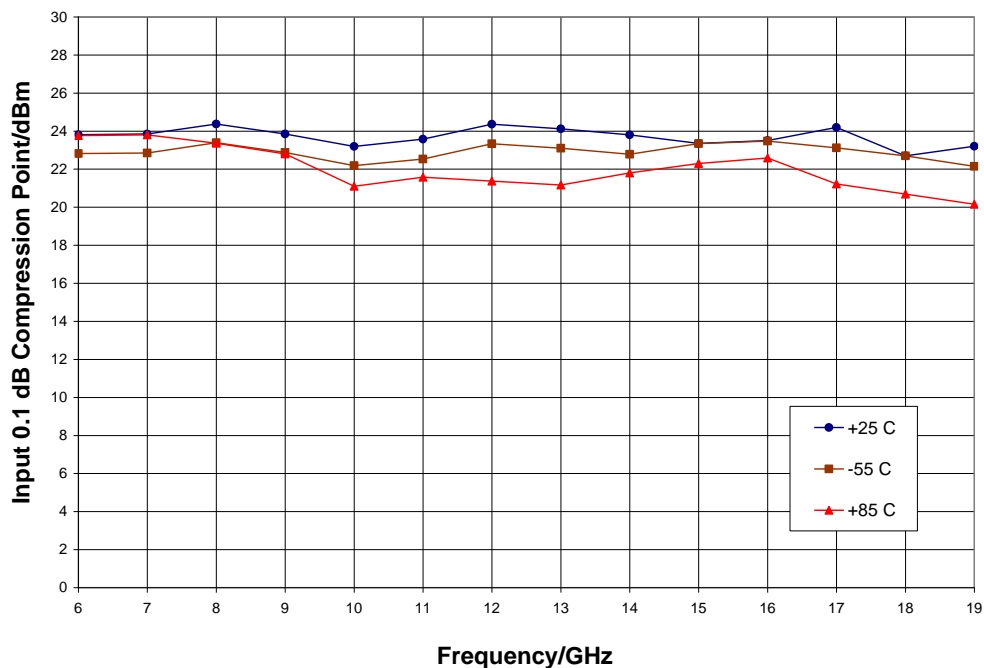
Bit Error versus Frequency, T$_A$ = 25° C
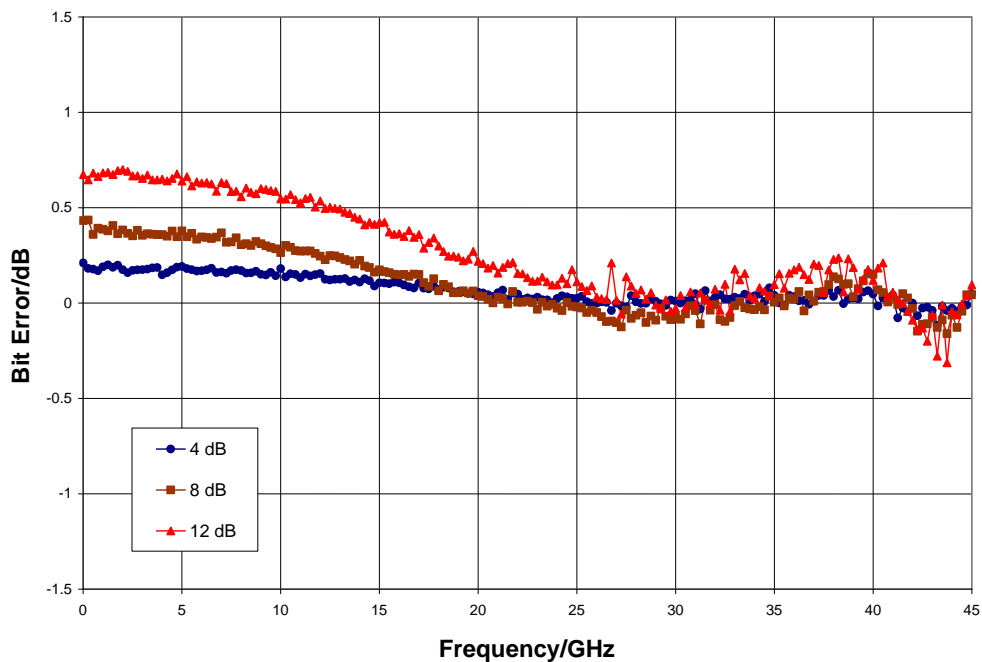
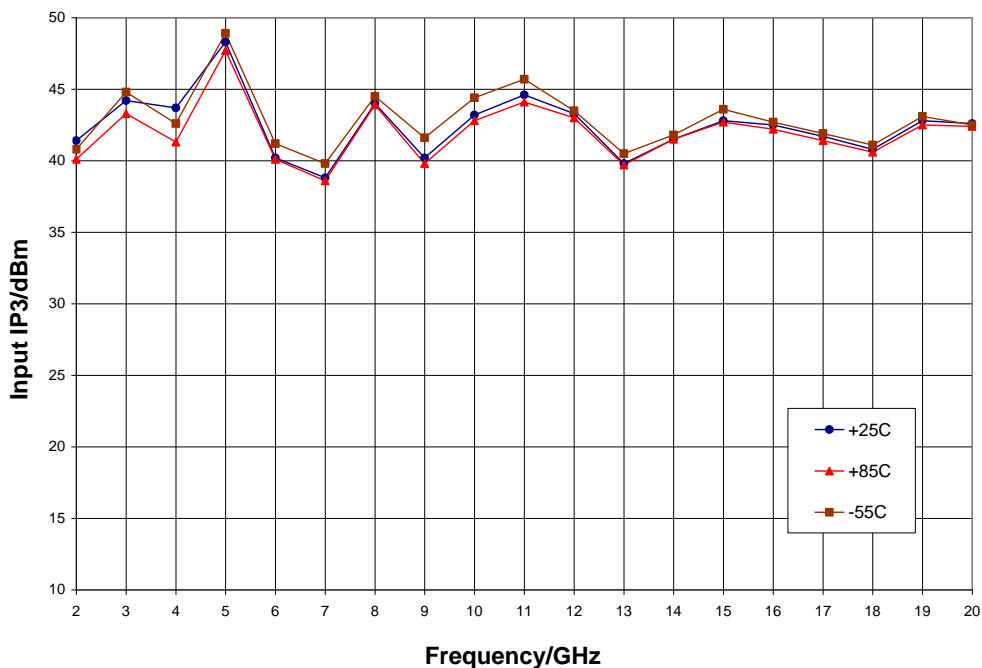**Relative Phase versus Frequency, T$_A$ = 25° C**
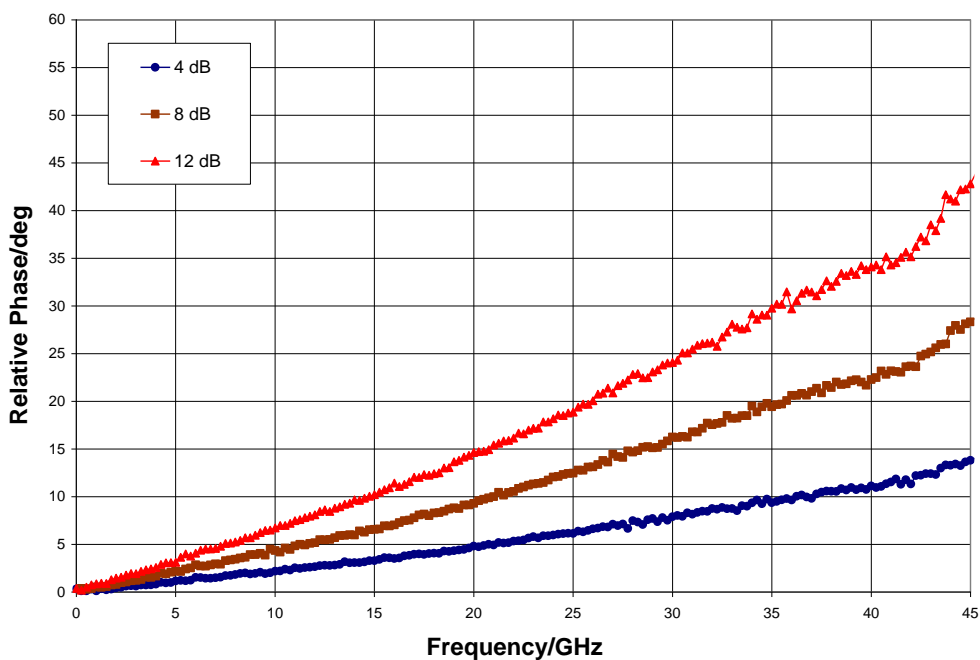
Typical Performance

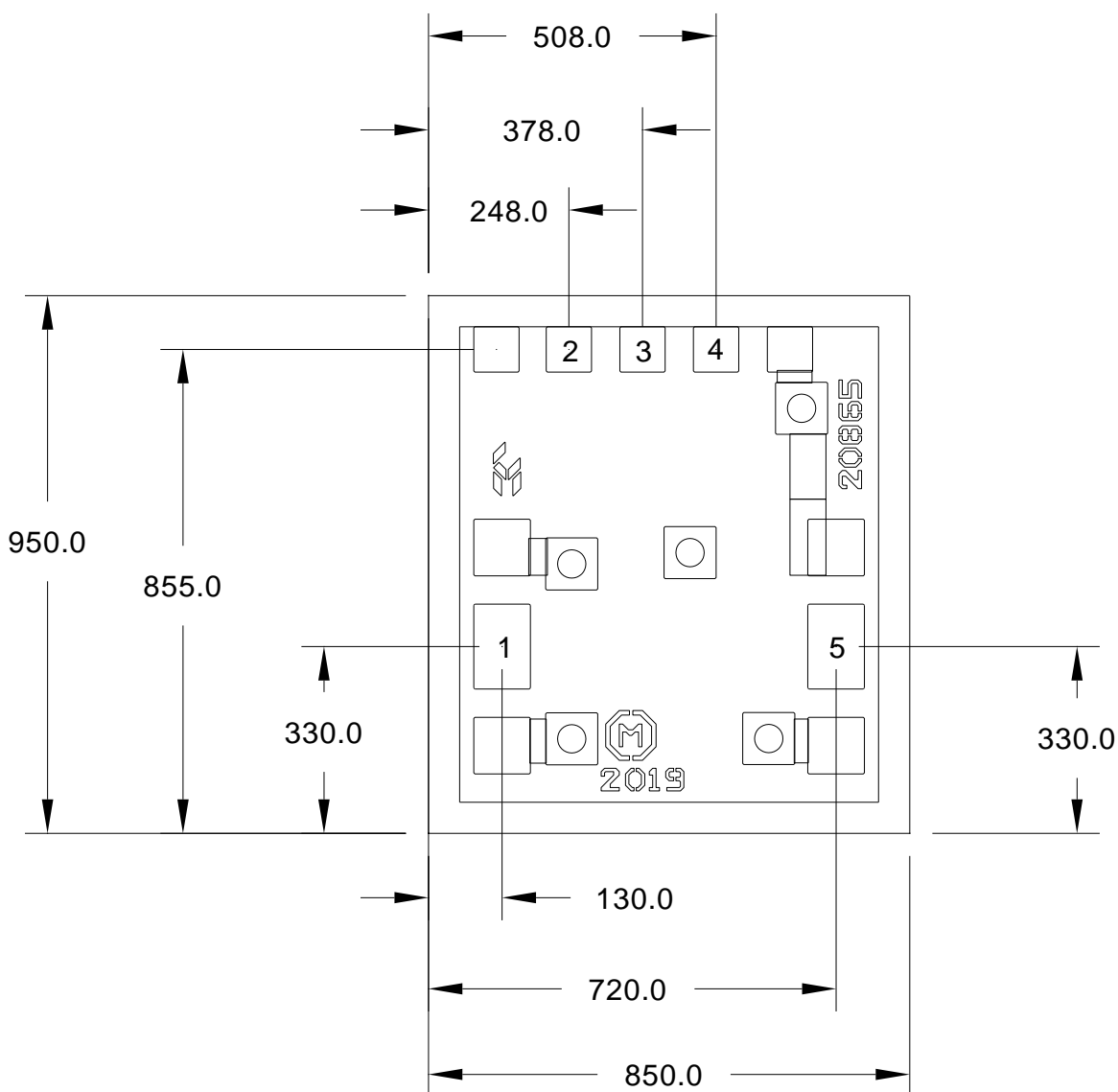**Input Power for 0.1 dB Compression (insertion loss state)**

Input IP3 versus Temperature (insertion loss state)

Mechanical Information

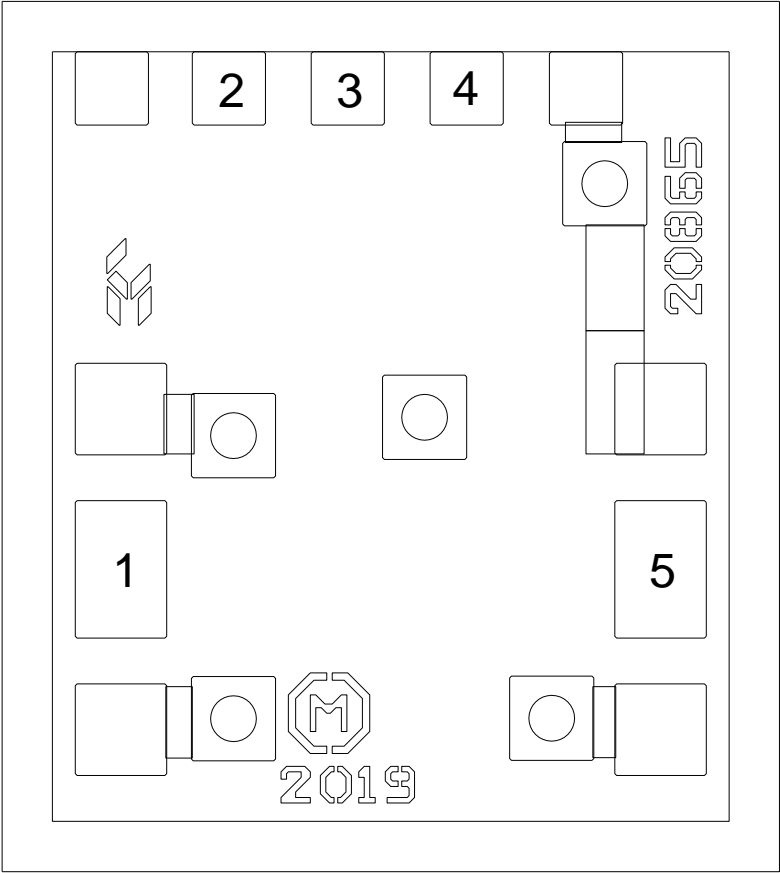**Die Outline (all dimensions in microns)**

Notes:
1. No connection required for unlabeled pads
2. Backside is RF and DC ground
3. Backside and bond pad metal: Gold
4. Die is 100 microns thick
5. DC bond pads (2, 3, 4) are 80 x 80 microns square
6. RF bond pads (1, 5) are 100 x 150 microns

Pad Description

Pad Diagram

Functional Description

| Pad	Function	Description	Schematic
1, 5	RF1, RF2	50 ohm matched	
2	V_{ee}	Negative bias -5 V	
3, 4	P0, P1	Bit control voltages, see truth table for values	
Backside	Ground	Connect to RF / DC ground	

Applications Information

Assembly Guidelines

The backside of the CMD282 is RF ground. Die attach should be accomplished with electrically and thermally conductive epoxy only. Eutectic attach is not recommended. Standard assembly procedures should be followed for high frequency devices. The top surface of the semiconductor should be made planar to the adjacent RF transmission lines, and the RF decoupling capacitors placed in close proximity to the DC connections on chip.

RF connections should be made as short as possible to reduce the inductive effect of the bond wire. Use of a 0.8 mil thermosonic wedge bonding is highly recommended as the loop height will be minimized. The RF input and output require a single bond wire as shown.

The semiconductor is 100 um thick and should be handled by the sides of the die or with a custom collet. Do not make contact directly with the die surface as this will damage the monolithic circuitry. Handle with care.

Assembly Diagram
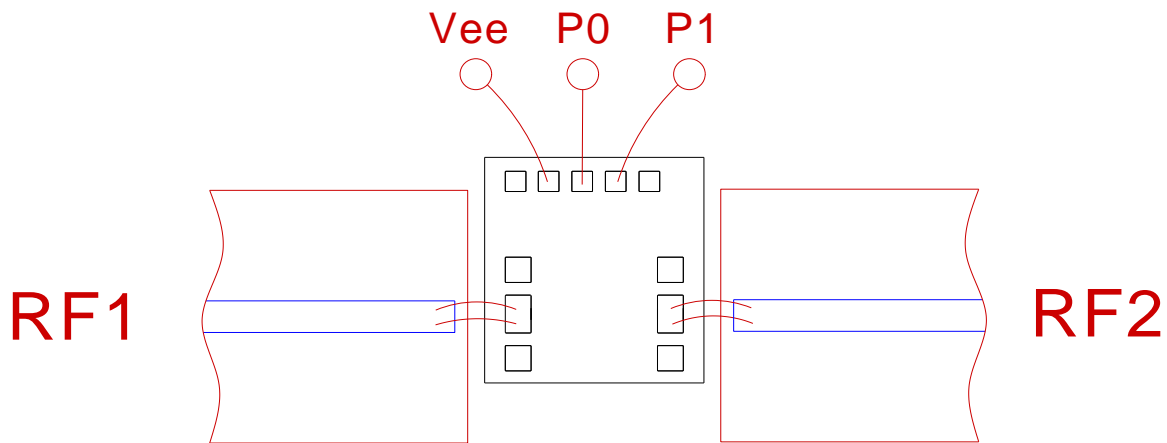
Biasing and Operation

The CMD282 has two control lines and a V_{ee} bias port. The CMD282 will not operate unless V_{ee} is applied to the MMIC.

GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.

Handling Precautions

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	Class 1A	ESDA / JEDEC JS-001-2012

Caution!
ESD-Sensitive Device

RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:
- Lead Free
- Antimony Free
- TBBP-A ($C_{15}H_{12}Br_40_2$) Free
- SVHC Free
- PFOS Free
- Halogen Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

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